

# TSTE05 Elektronik & mätteknik

## Föreläsning 12

### Dioder

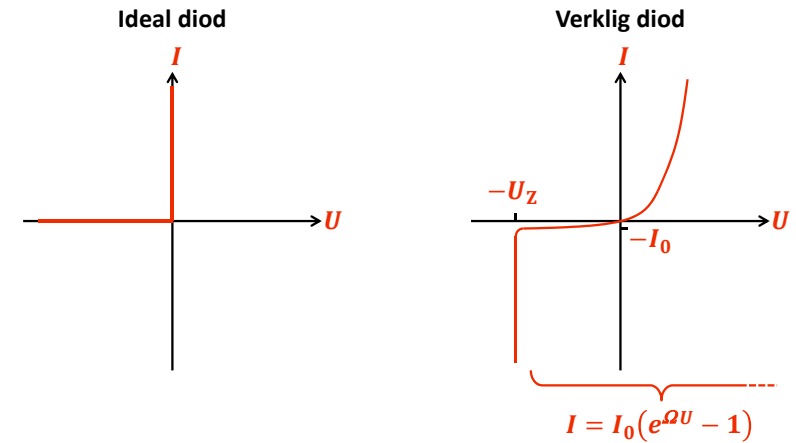
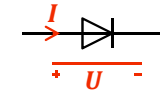
### Bipolartransistorer - Inledning

Mikael Olofsson

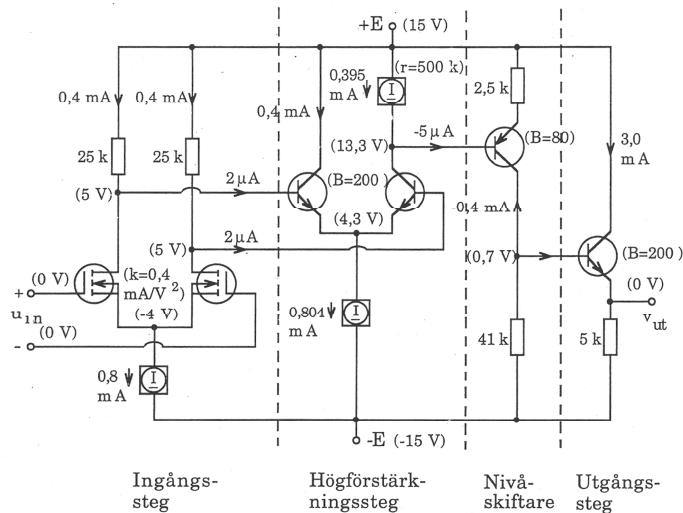
Institutionen för Systemteknik (ISY)

Ämnesområdet Elektroniska kretsar och system

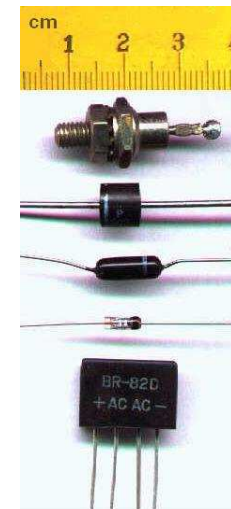
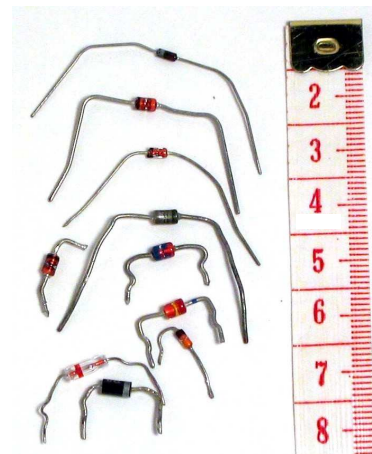
## Dioder



## Operationsförstärkare



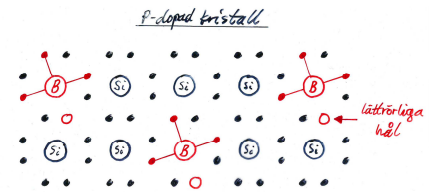
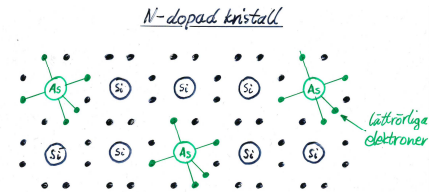
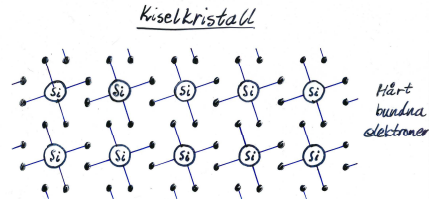
## Dioder – Exempel



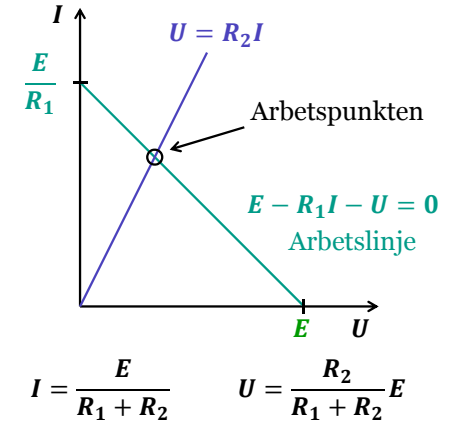
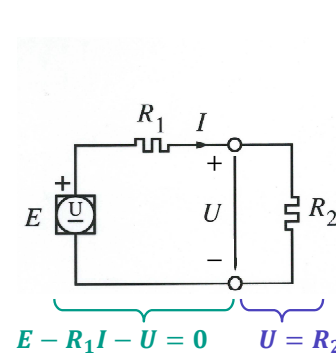
Källa: Wikipedia

# Halvledare

3 A		4 A		5 A	
3	±4, 2	±4, 2	±4, 2	±3, 5, 4, 2	±3, 5, 4, 2
5 B Bor 10.811	6 C Kol 12.0111	7 N Kväve 14.0067	13 Al Aluminium 26.9815	14 Si Kisel 28.086	15 P Fosfor 30.9738
3	4	±3, 5	3	4	±3, 5
31 Ga Gallium 69.72	32 Ge Germanium 72.59	33 As Arsenik 74.9216	49 In Indium 114.82	50 Sn Tenn 118.69	51 Sb Antimon 121.75
3	4, 2	±3, 5	3	4, 2	±3, 5
81 Tl Thallium 204.37	82 Pb Bly 207.19	83 Bi Bismut 208.980			

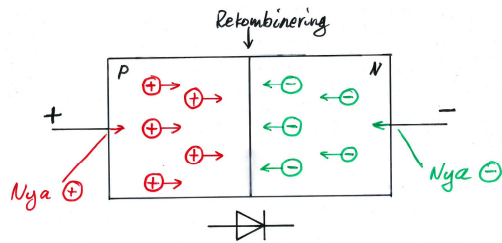


# Arbetspunktsbestämning – Introduktion

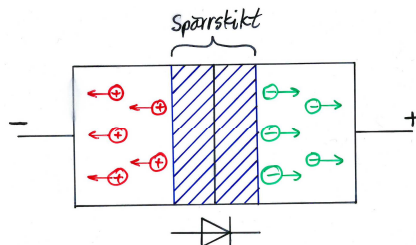


# Diodens funktion

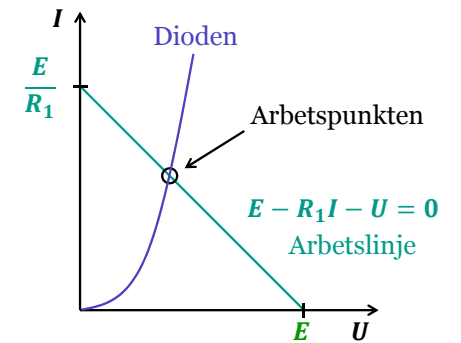
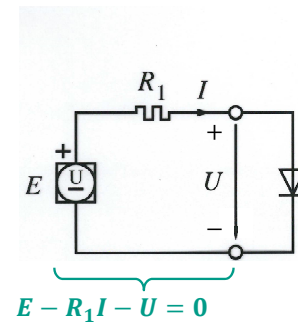
Framspänd diod:



Backspänd diod:

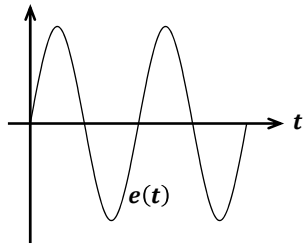
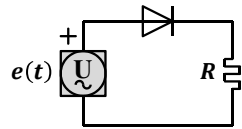


# Arbetspunktsbestämning för diod

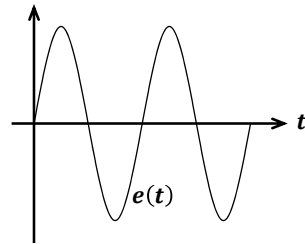
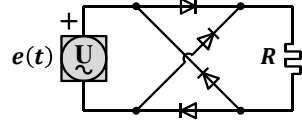


## Likriktning med diod 1(3)

Halvågslikriktning

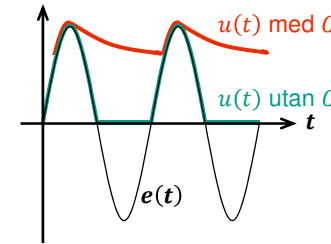
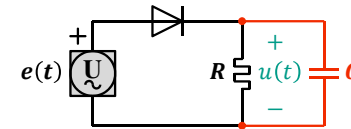


Helvågslikriktning

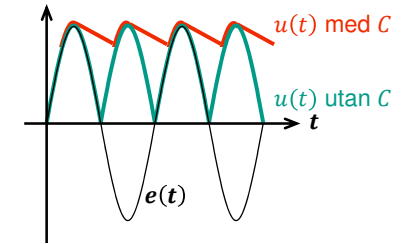
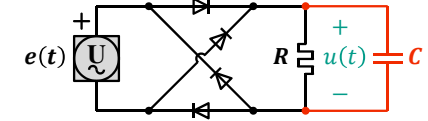


## Likriktning med diod 2(3)

Halvågslikriktning

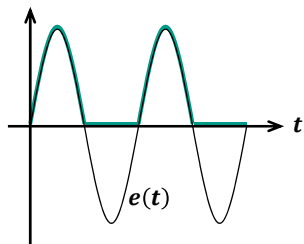
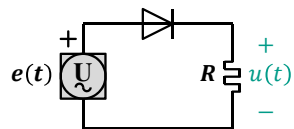


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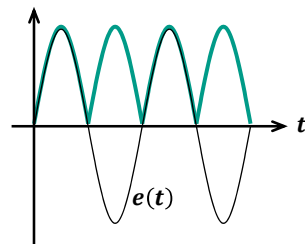
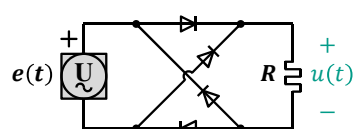


## Likriktning med diod 2(3)

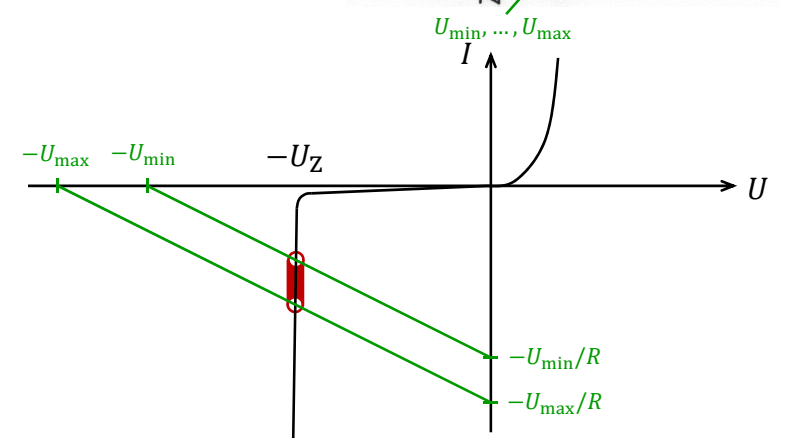
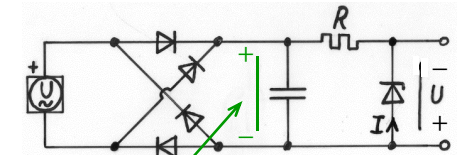
Halvågslikriktning



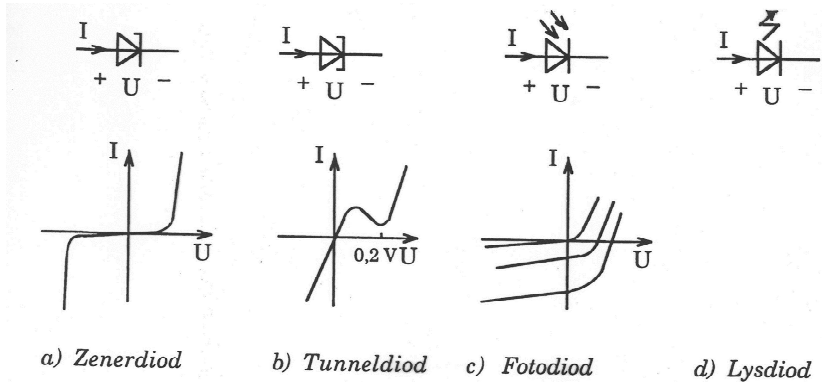
Helvågslikriktning



## Stabilisering med zenerdiod



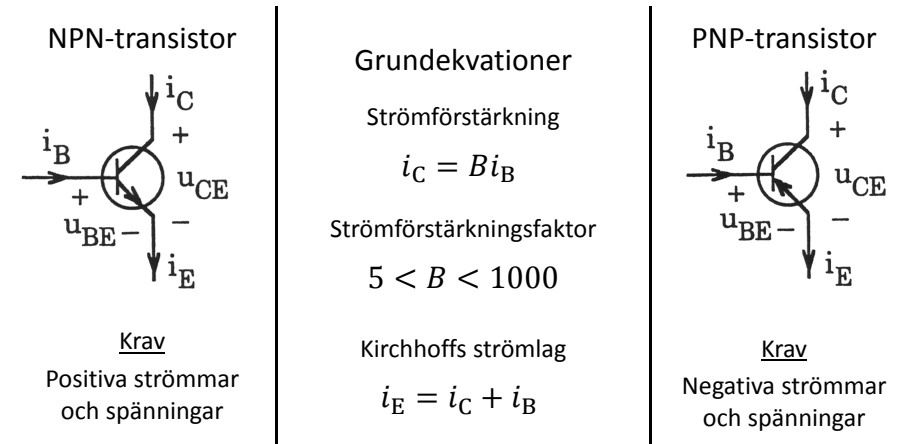
## Andra slags dioder



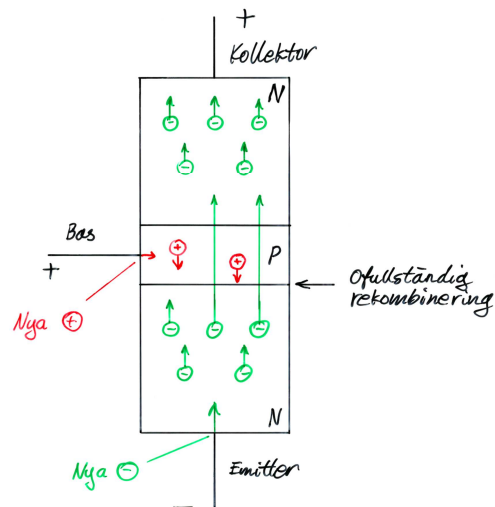
Figur 3.72 Symbol och karakteristik för några olika diodtyper.

Figur 3.72 ur Söderkvist

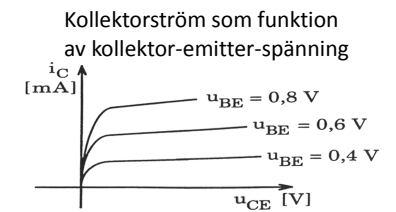
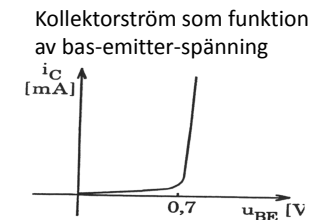
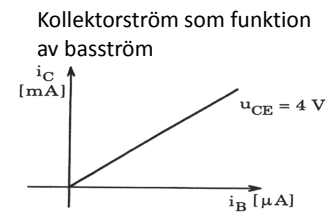
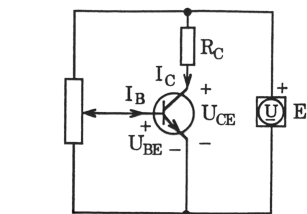
## Bipolartransistorer – Variabler och referensriktningar



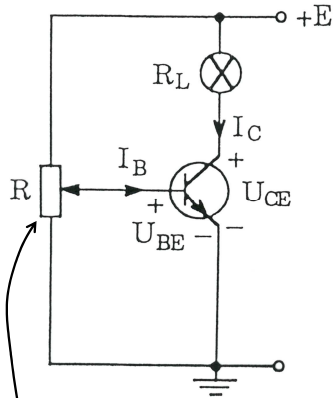
## Bipolartransistorn - NPN



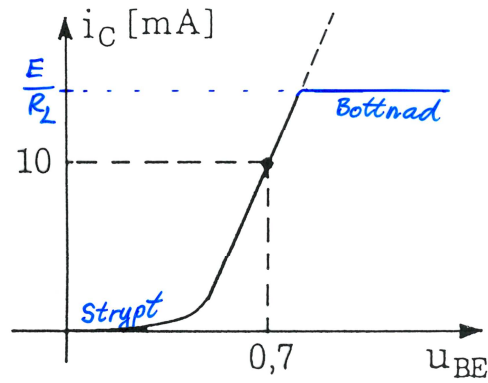
## Bipolartransistorer – Några samband



# Strömstyrning med NPN-transistor

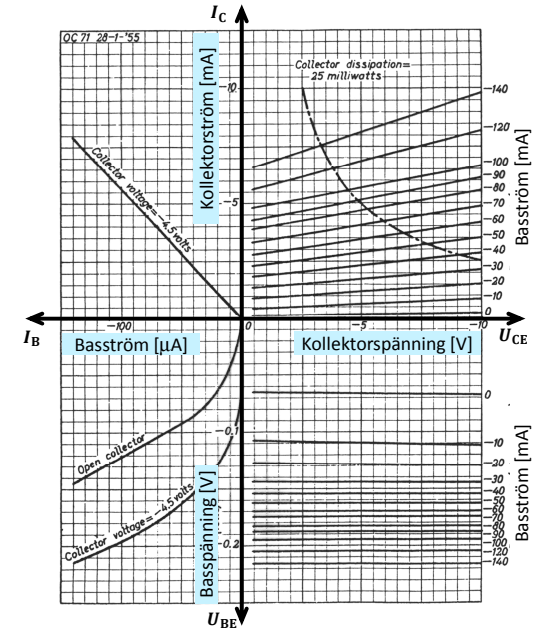


Potentiometer (vridmotstånd)

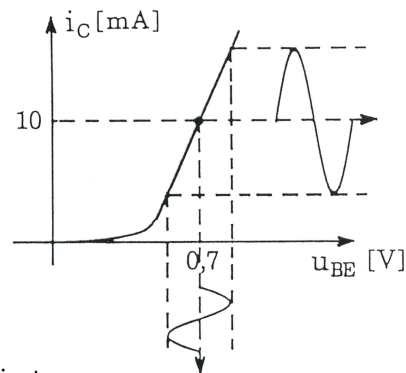
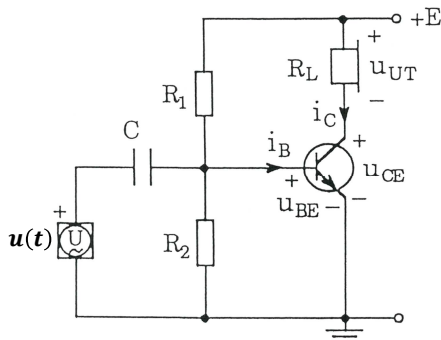


# Fullständigt kurvblad för PNP-transistor

Observera: Fyra diagram i ett. Varje kvadrant är ett separat diagram



# Förstärkning av signalspänning



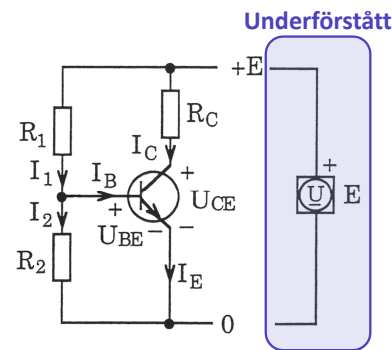
Obs! Signalspänningen  $u_{be}(t) = u(t)$  om C är stor.

$$u_{BE}(t) = U_{BEQ} + u_{be}(t)$$

$$i_C(t) = I_{CQ} + i_c(t)$$

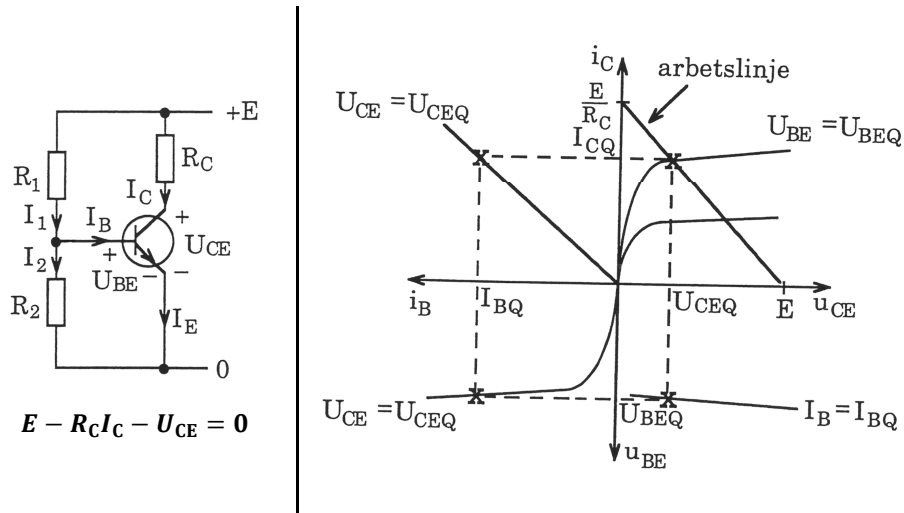
$$u_{UT}(t) = R_L i_c(t)$$

# Enkel transistorkoppling – Arbetslinje



$$KVL: E - R_C I_C - U_{CE} = 0$$

# Enkel transistorkoppling – Arbetspunkt



Mikael Olofsson  
ISY/EKS

www.liu.se

# GE-steg – Gemensam emitter

